# NSN 5962-01-288-6901

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Body Length:
0.840 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
0.185 inches
Maximum Power Dissipation Rating:
739.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Programmable and bipolar and programmed and 3-state output
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
6 input
Case Outline Source And Designator:
D-2 mil-m-38510
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
80.00 nanoseconds propagation delay time, low to high level or
output
Memory Device Type:
Prom
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bulle
format; excludes commercial catalogs, industry directories, and
environmental and performance requirements and test conditions
Terminal Type And Quantity:
16 printed circuit

# evel output and 80.00 nanoseconds propagation delay time, high to low level

e bulletins, brochures, etc., that reflect specification type data in specification s, and similar trade publications, reflecting general type data on certain ditions that are shown as "typical", "average", "", etc.).

### **Specification Data:**

81349-mil-m-38510/207 government specification

## Shelf Life:

N/a

# Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

